

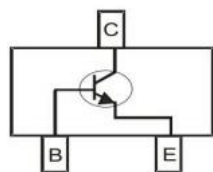


SOT-23 Bipolar Transistor 双极型三极管



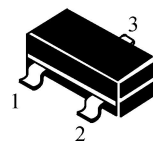
■ Features 特点

NPN General Purpose 通用



SOT-23

- 1. BASE
- 2. EMITTER
- 3. COLLECTOR



■ Absolute Maximum Ratings 最大额定值

Characteristic 特性参数	Symbol 符号	BC817- 16/25/40 -6AF	BC818- 16/25/40 -6AF	Unit 单位
Collector-Base Voltage 集电极基极电压	V_{CBO}	50	30	V
Collector-Emitter Voltage 集电极发射极电压	V_{CEO}	45	25	V
Emitter-Base Voltage 发射极基极电压	V_{EBO}	5	5	V
Collector Current 集电极电流	I_C	500		mA
Power dissipation 耗散功率	$P_C(T_a=25^{\circ}C)$	300		mW
Thermal Resistance Junction-Ambient 热阻	$R_{\theta JA}$	417		$^{\circ}C/W$
Junction and Storage Temperature 结温和储藏温度	T_J, T_{stg}	-55to+150 $^{\circ}C$		

■ Device Marking 产品打标

H_{FE}		100-250(-16-6AF)	160-400(-25-6AF)	250-600(-40-6AF)
Mark	BC817	6A	6B	6C
	BC818	6E	6F	6G

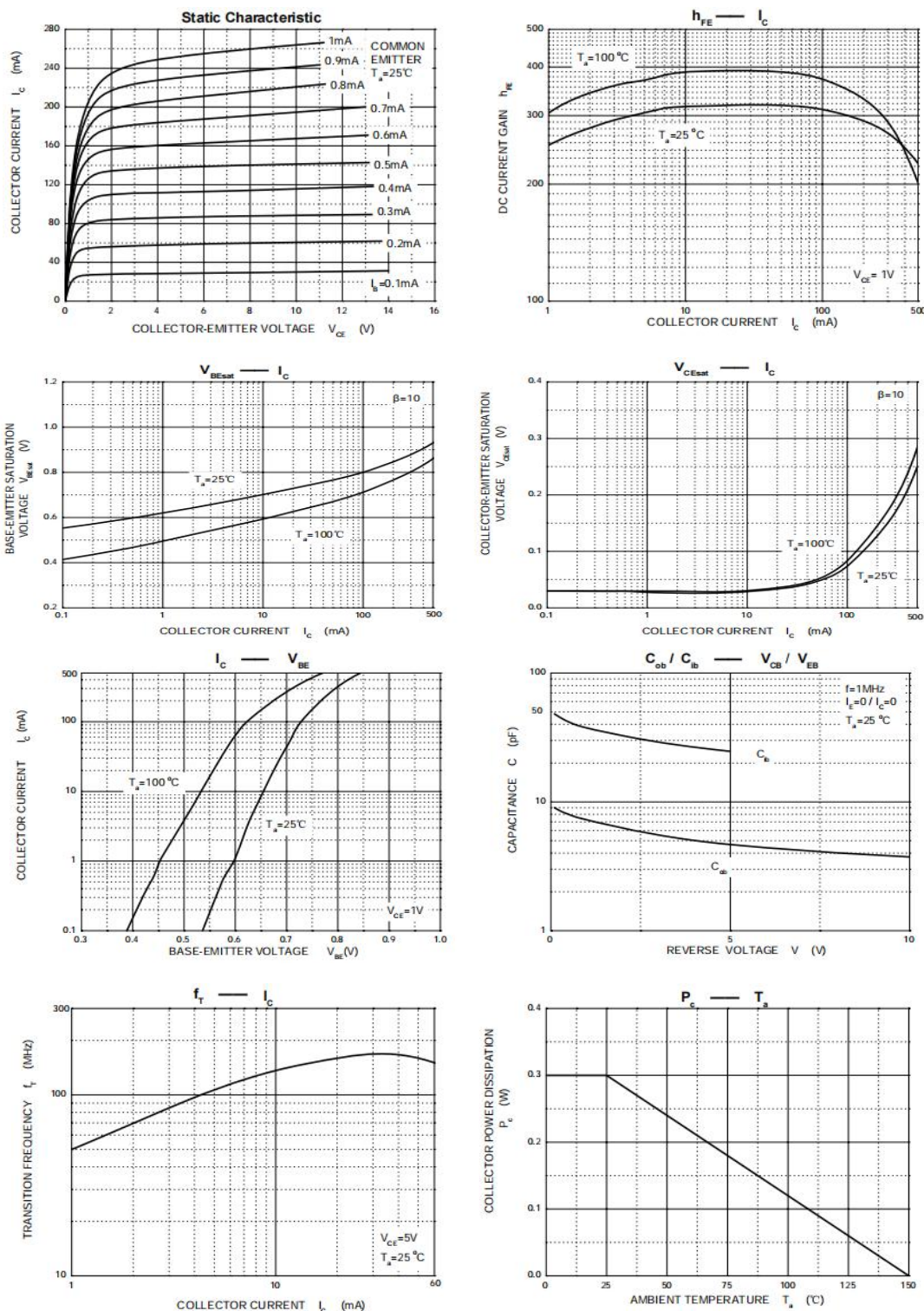


■Electrical Characteristics 电特性

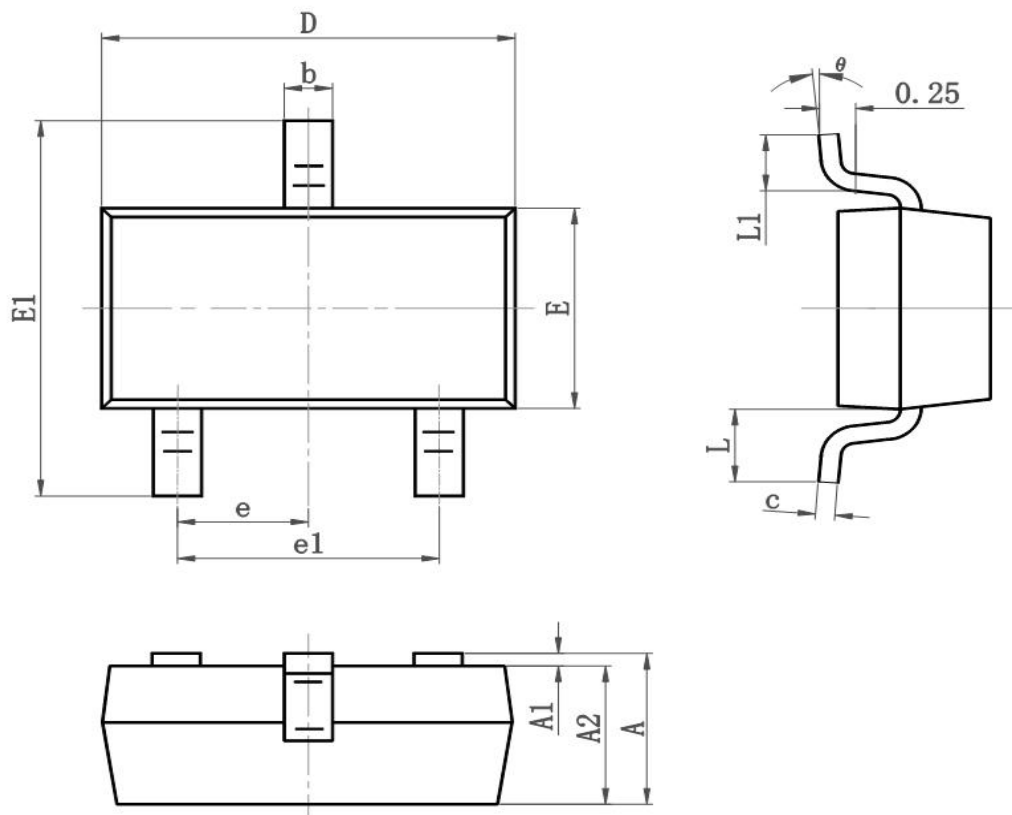
($T_A=25^{\circ}\text{C}$ unless otherwise noted 如无特殊说明, 温度为 25°C)

Characteristic 特性参数		Symbol 符号	Min 最小值	Type 典型值	Max 最大值	Unit 单位
Collector-Base Breakdown Voltage 集电极基极击穿电压 ($I_C=10\mu\text{A}$, $I_E=0$)	BC817-16/25/40-6AF BC818-16/25/40-6AF	BV_{CBO}	50 30	—	—	V
Collector-Emitter Breakdown Voltage 集电极发射极击穿电压 ($I_C=10\text{mA}$, $I_B=0$)	BC817-16/25/40-6AF BC818-16/25/40-6AF	BV_{CEO}	45 25	—	—	V
Emitter-Base Breakdown Voltage 发射极基极击穿电压 ($I_E=10\mu\text{A}$, $I_C=0$)		BV_{EBO}	5	—	—	V
Collector-Base Leakage Current 集电极基极漏电流	BC817-16/25/40-6AF ($V_{CB}=50\text{V}, I_E=0$) BC818-16/25/40-6AF ($V_{CB}=30\text{V}, I_E=0$)	I_{CBO}	—	—	100	nA
Emitter-Base Leakage Current 发射极基极漏电流 ($V_{EB}=4\text{V}$, $I_C=0$)		I_{EBO}	—	—	100	nA
DC Current Gain 直流电流增益 ($V_{CE}=1\text{V}, I_C=100\text{mA}$)	BC817/BC818-16-6AF BC817/BC818-25-6AF BC817/BC818-40-6AF	H_{FE}	100 160 250	—	250 400 600	
DC Current Gain 直流电流增益($V_{CE}=1\text{V}, I_C=500\text{mA}$)		H_{FE}	40			
Collector-Emitter Saturation Voltage 集电极发射极饱和压降($I_C=500\text{mA}$, $I_B=50\text{mA}$)		$V_{CE(sat)}$	—	—	0.7	V
Base-Emitter Saturation Voltage 基极发射极饱和压降($I_C=500\text{mA}$, $I_B=50\text{mA}$)		$V_{BE(sat)}$	—	—	1.2	V
Base-Emitter On Voltage 基极发射极导通电压($V_{CE}=1\text{V}$, $I_C=500\text{mA}$)		$V_{BE(on)}$	—	—	1.2	V
Transition Frequency 特征频率($V_{CE}=5\text{V}$, $I_C=10\text{mA}$)		f_T	100	—	—	MHz
Output Capacitance 输出电容($V_{CB}=10\text{V}$, $I_E=0$, $f=1\text{MHz}$)		C_{ob}	—	10	—	pF

■ Typical Characteristic Curve 典型特性曲线



■Dimension 外形封装尺寸



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.050	0.055
E1	2.250	2.550	0.089	0.100
e	0.900	1.00	0.035	0.039
e1	1.800	2.000	0.071	0.079
L	0.500	0.600	0.020	0.024
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°